

# Gas sensor based on tungsten trioxide (WO<sub>3</sub>) nanoparticles

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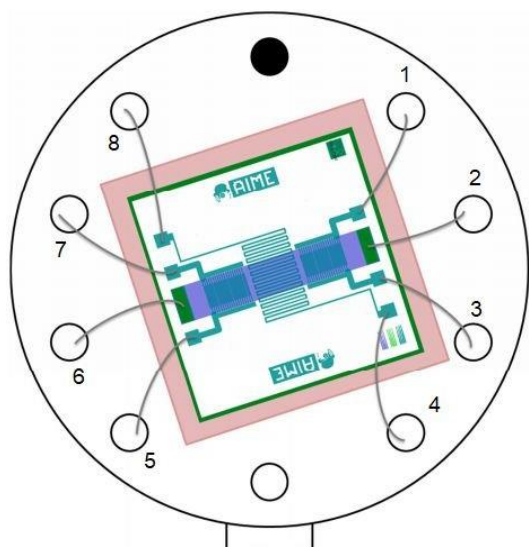
## Features of the sensor:

- Detection of  $\text{NH}_3$  (Ammonium hydroxide)
- Detection of  $\text{CH}_3\text{CH}_2\text{OH}$  (Ethanol)
- Quick response
- Heater resistor included (Polysilicon)
- High impedance
- Temperature sensor (Aluminium)

## Description:

This gas sensor has been developed at the AIME clean room of INSA Toulouse to monitor gases' concentration (Ammonium hydroxide, Ethanol and air). This sensor is based on two symmetrical interdigital combs composed of tungsten nanoparticles. The resistance of the sensor is hence related to these nanoparticles' concentration that varies with the gas in the air. Besides, this sensor integrates a doped polysilicon heater and aluminum resistors used to handle and control the temperature. Depending on the amount of gas surrounding the sensor and by connecting it to an electronic circuit, we can get its resistance and thus find the concentration of gas.

## Pin Description and functions



Pin Number	Usage
1 - 3	Gas sensor (WO <sub>3</sub> nanoparticles integrated on interdigital aluminium combs)
2 - 6	Heater (Doped Polysilicon)
5 - 7	Gas sensor (WO <sub>3</sub> nanoparticles integrated on interdigital aluminium combs)
4 - 8	Temperature sensor (Aluminium resistor)

## Specifications

Type	Nanoparticle based sensor
Materials	<ul style="list-style-type: none"> <li>• Silicon</li> <li>• Doped polysilicon</li> <li>• Aluminium</li> <li>• Tungsten trioxide nanoparticle</li> </ul>
Sensor type	Active sensor
Nature of output signal	Analog signal
Nature of measurand	Resistance mesure
Detectable gaz	<ul style="list-style-type: none"> <li>• NH<sub>3</sub> (Ammonium hydroxide)</li> <li>• CH<sub>3</sub>CH<sub>2</sub>OH (Ethanol)</li> </ul>
Mounting	Through hole fixed
Response time	< 30s
Recuperation time	> 100s
Nomiale temperature	[423K - 573K]
Deterioration temperature	573K +

## Physical Characteristics

Package	Package 10-Lead TO-5 metal can
Diameter	10mm
Height	25mm

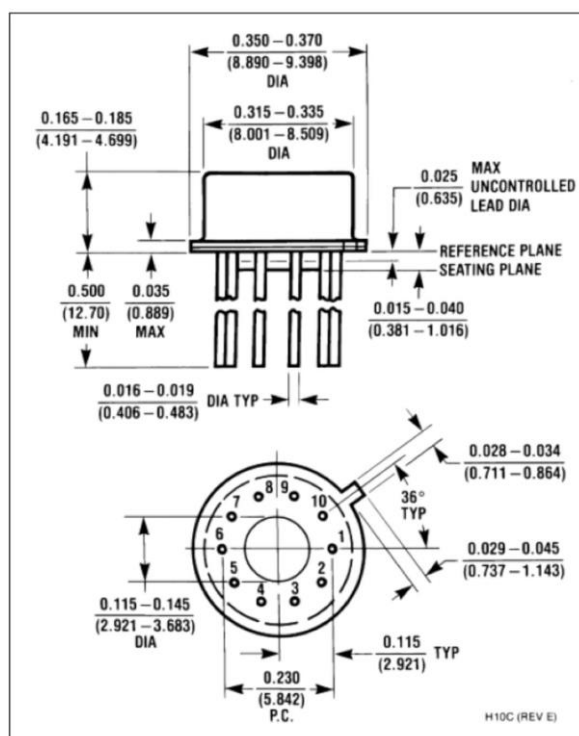
## Recommended Operating Conditions

Temperature	25°C+5°C
Pressure	101,325 Pa

## Electrical Characteristics

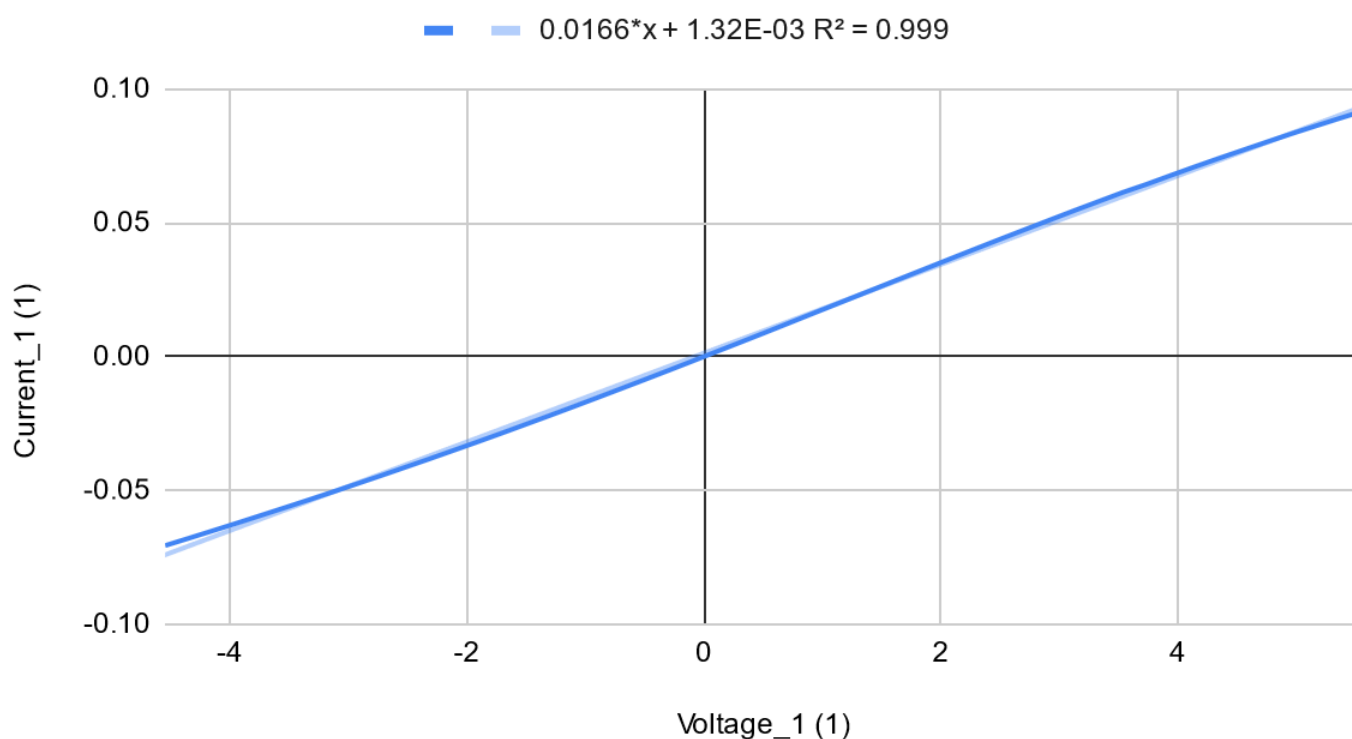
	Aluminum	Polysilicon
Nominal Use	0 - 5V	0 - 11V
Non Deterioration Use	5V - 10V	11V - 15V

## Dimensions



## Characteristic graphs of resistances and currents in standard test conditions

### Current\_1 (1) vs Voltage\_1 (1) : nominale



*Figure1: Current and resistance response as a function of voltage (RESISTANCE ALU) on nominal mode*

### Current\_1 (1) vs Voltage\_1 (1) : Non détérioration

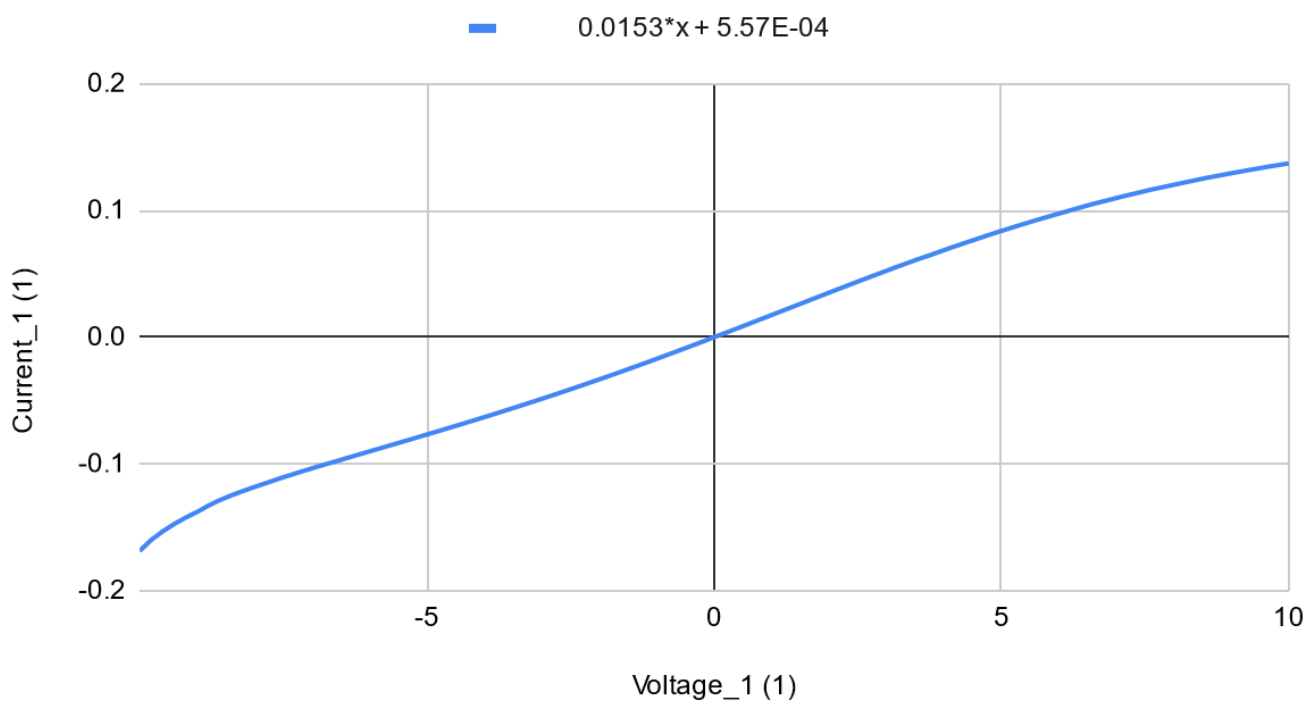


Figure2: Current and resistance response as a function of voltage (RESISTANCE ALU) on “non deterioration” mode

## Current\_1 (1) vs Voltage\_1 (1) : nominale

— 0.0119\*x + 1.62E-03 R<sup>2</sup> = 0.999

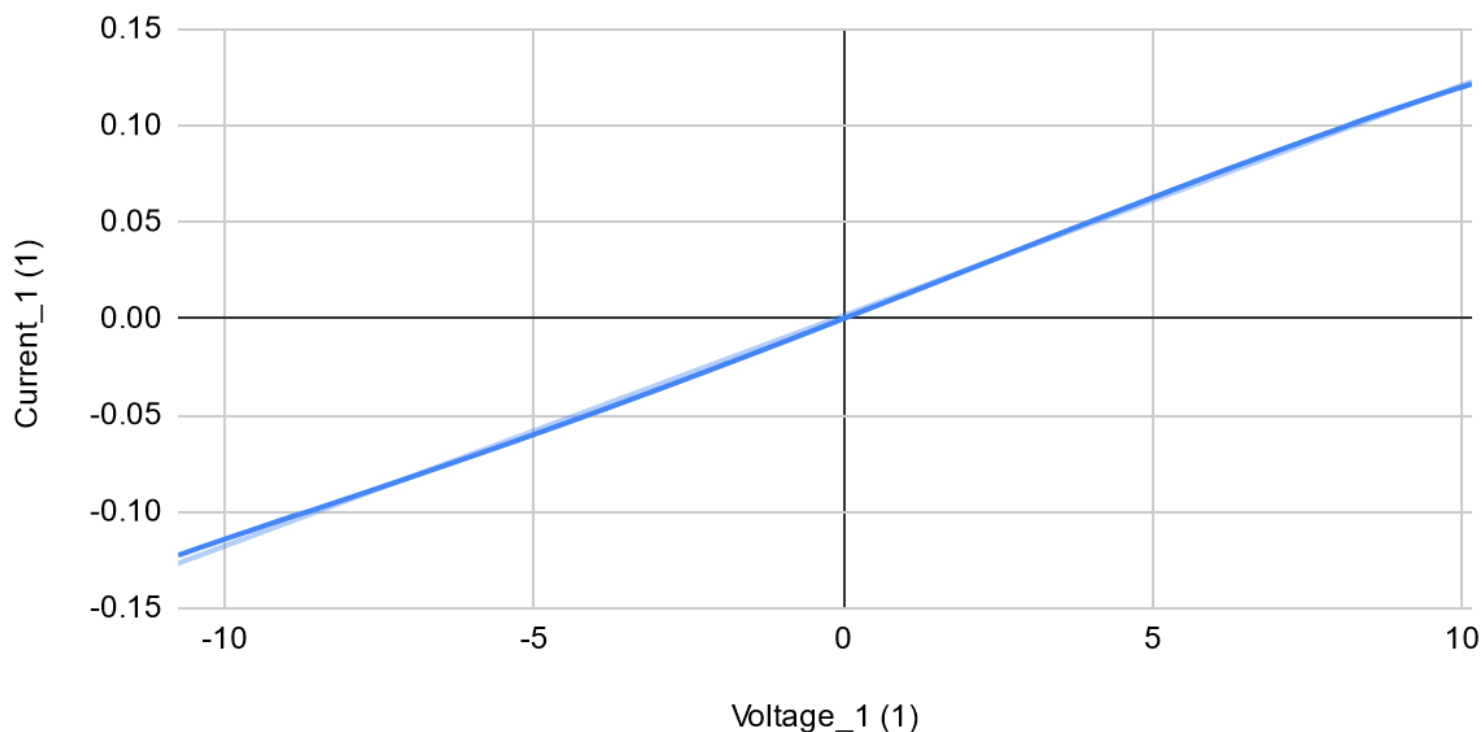


Figure3: Current and resistance response as a function of voltage (RESISTANCE POLY) on “nominal” mode

## Current\_1 (1) vs Voltage\_1 (1) : non destruction

— 0.0117\*x + 2.72E-04 R<sup>2</sup> = 0.998

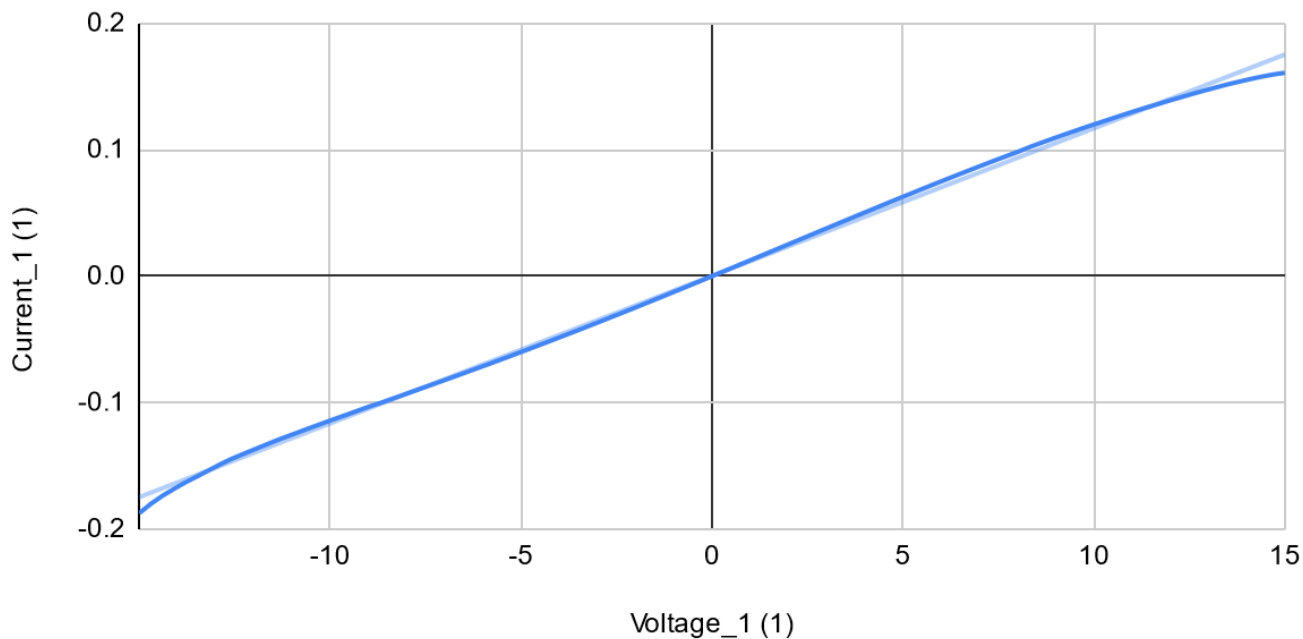


Figure4: Current and resistance response as a function of voltage (RESISTANCE POLY) on “non deterioration” mode

## Current\_1 (1) vs Voltage\_1 (1)

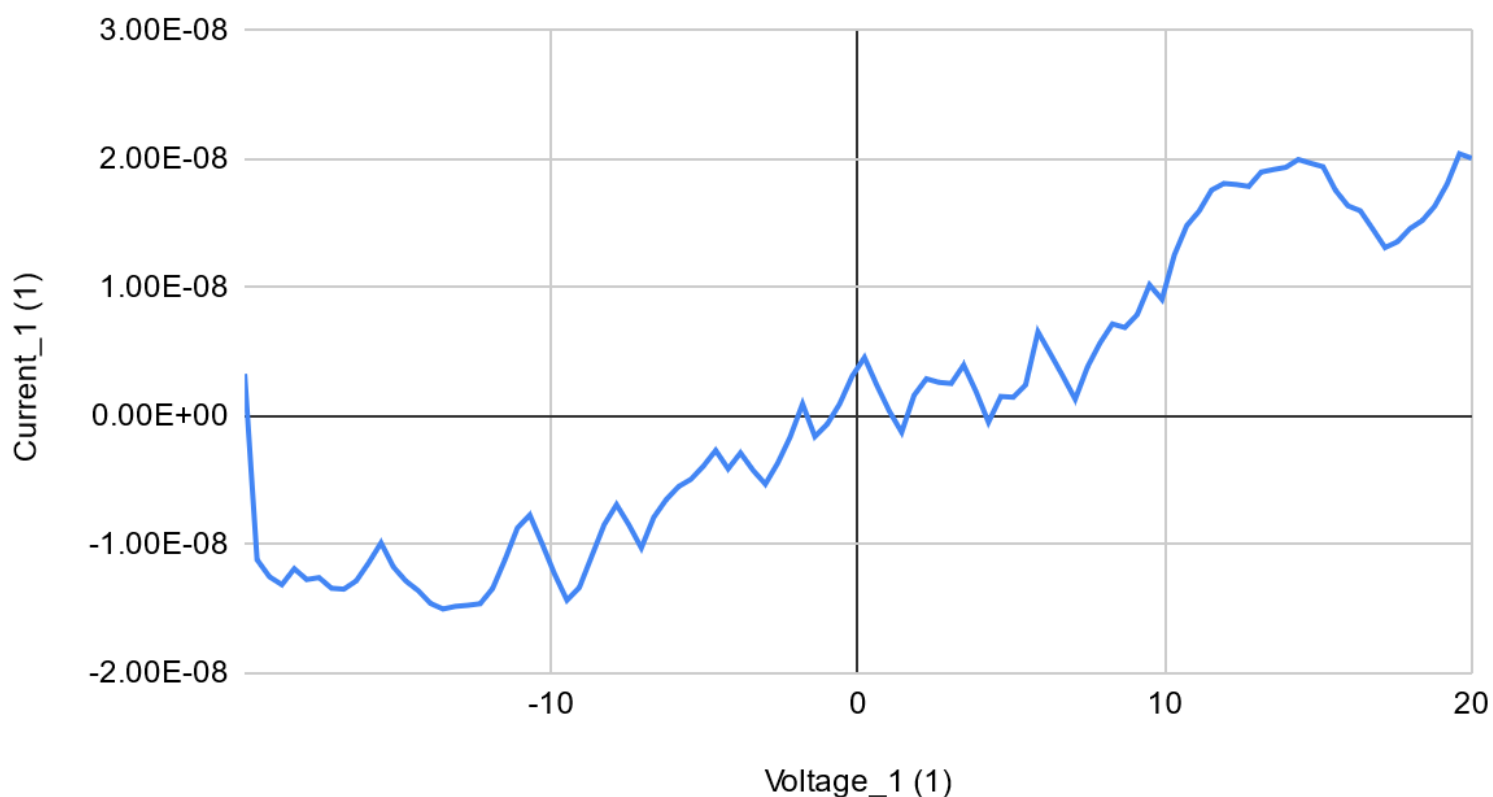
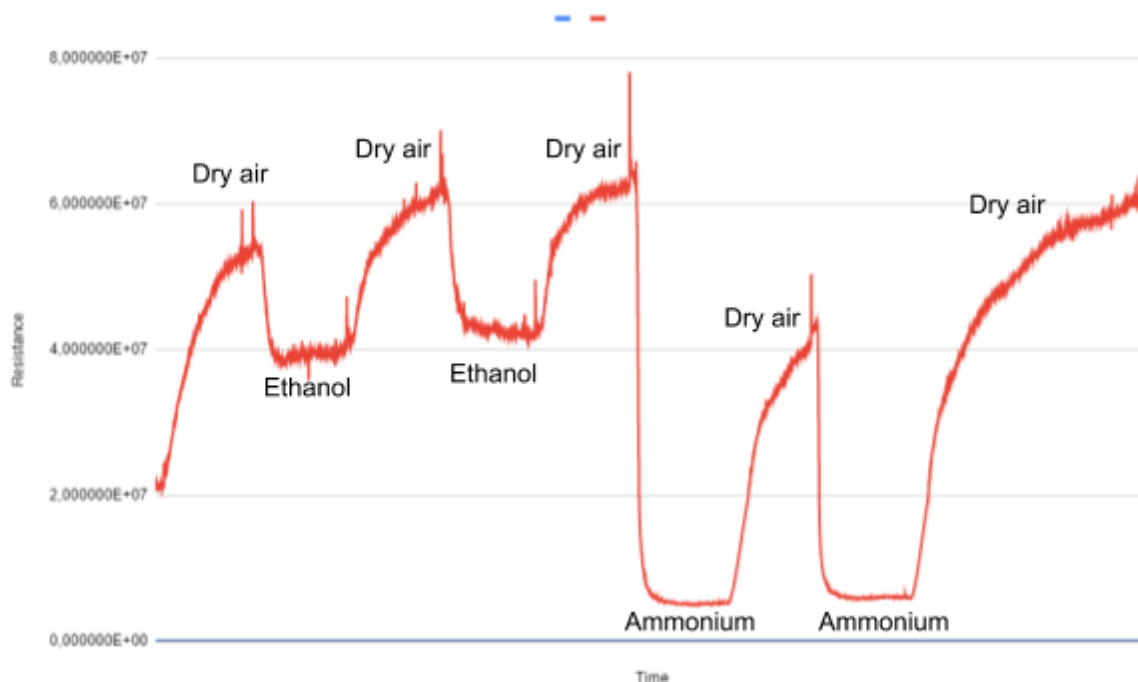


Figure5: Current and resistance response as a function of voltage (RESISTANCE CAPTEUR) on “nominal” mode

## Procedure for the characterization of the sensor

15s	120s	120s	120s	120s	120s	120s	120s	120s	...
Ø	Dry air	Ethanol 1000ppm	Dry air	Ethanol 1000ppm	Dry air	NH <sub>3</sub> 1000ppm	Dry air	NH <sub>3</sub> 1000ppm	Dry air

## Results at 523K



*Figure6: Results at 523K, resistance response as a function of time*

By measuring the resistance of the resistance, we outline the sensor characteristic. The first half of the test phase was the response under ethanol gas, while the last half was under ammonia. The drop in the resistance shows the gas sensor response to a given gas while the increase in resistance illustrates the process of rebuilding the sensor.

N <sub>2</sub> O <sub>2</sub>		CH <sub>3</sub> CH <sub>2</sub> OH		NH <sub>3</sub>	
DR/R0 (%)	kN <sub>2</sub> O <sub>2</sub> - tN <sub>2</sub> O <sub>2</sub>	DR/R0 (%)	kEth - tEth	DR/R0 (%)	kNH <sub>3</sub> - tNH <sub>3</sub>
-50%	0,1 Hz - 10s	-27,00%	0.04 Hz - 25s	-150,00%	0.167 Hz - 6s

Note : The response at 453K provides a more sensitive response than at 523K. The detection of a gas causes a more significant reaction with a better response time. However, the resistor reconstitution time is much longer and is not suitable for high frequency use.



## Possible Conditioning Circuit for measurement with Arduino Uno

The entry impedance of the Arduino is much lower than the impedance of the Sensor. We must therefore put in place a conditioning circuit. This conditioning circuit is an amplifier that allows us to shape the sensor response to obtain an exploitable signal that our Arduino will take care of.

Here is below a possible circuit:

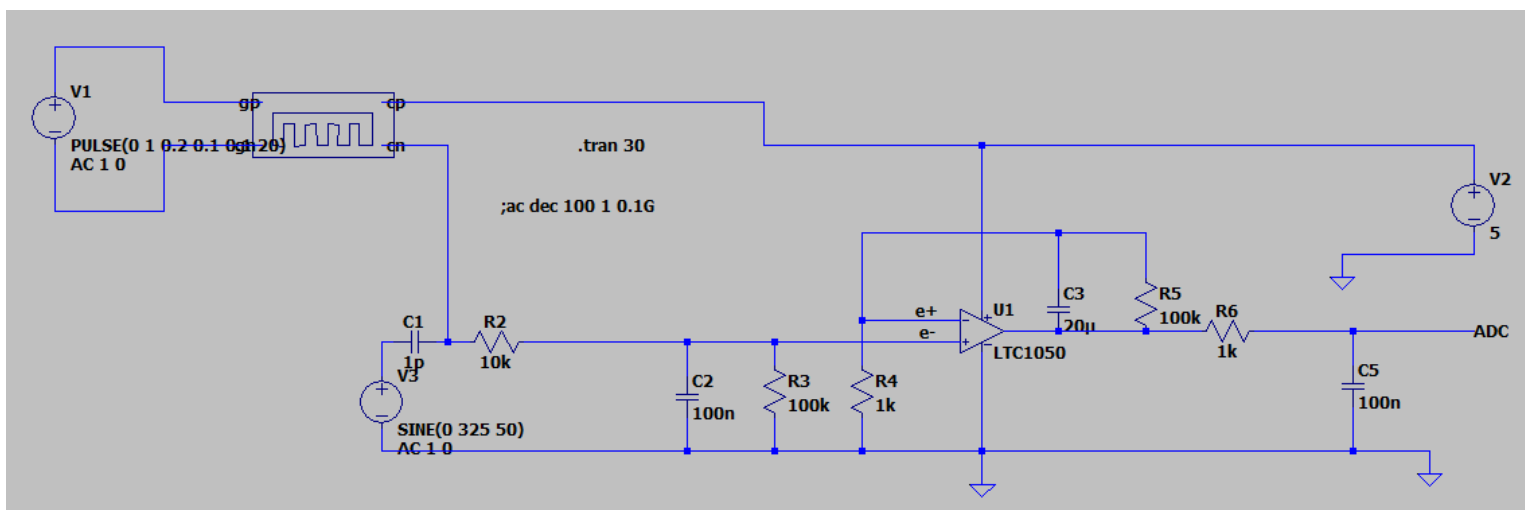


Figure7: File LTSpice Simulation

For input, we apply a PULSE signal with 5 seconds at HIGH LEVEL (1 digital) and we observe in output the V<sub>ADC</sub> which is also the input voltage of our Arduino board.

We observe that when  $I_x$  change its state from LOW to HIGH or HIGH to LOW,  $V_{ADC}$  also changes its state with a very small delay. For  $I_x$  varies from 200nA to 400nA, we obtain  $V_{ADC}$  varies from 2V to 4V, so the gain of our amplifier circuit equals to:  $10^7$  (V/nA)

The  $V_{ADC}$  signal (red) “follows” very well the evolution of our input signal ( $I_x$ ).

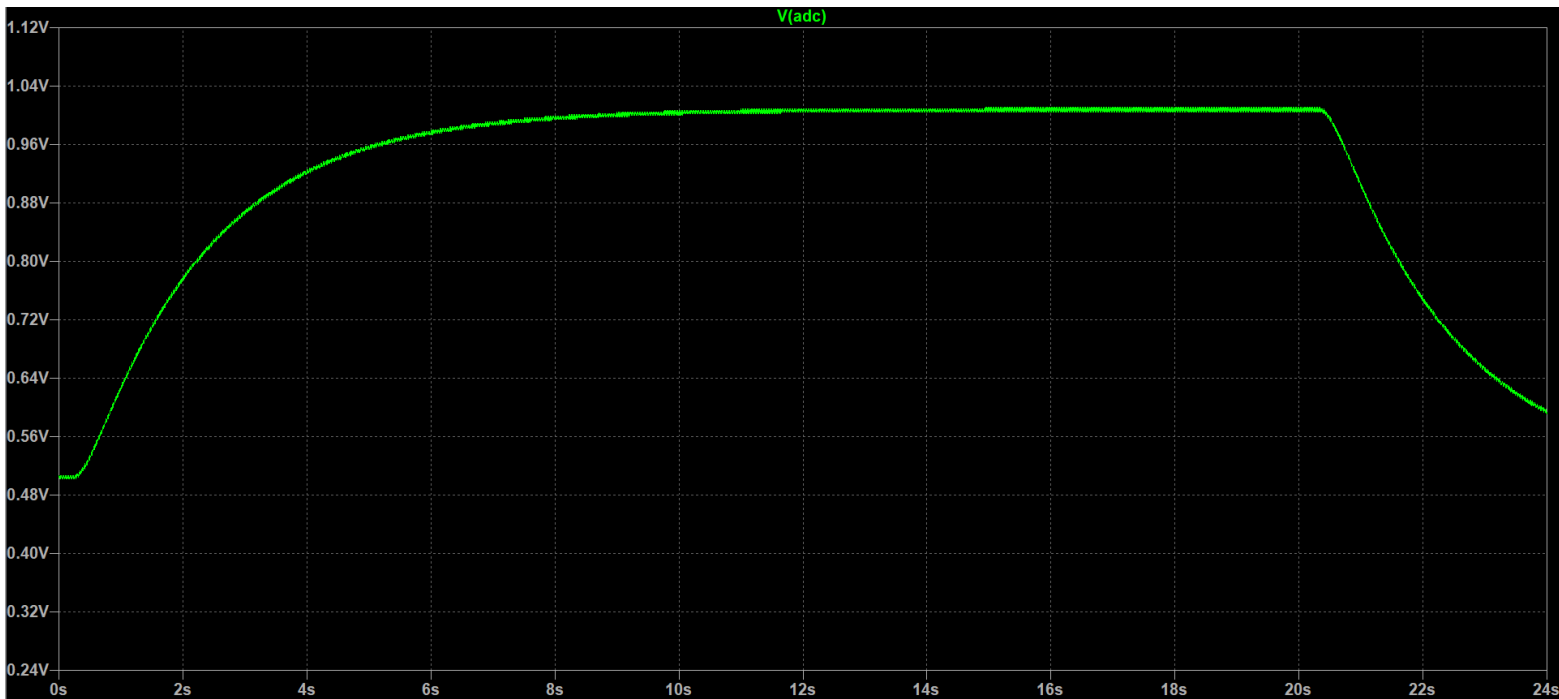
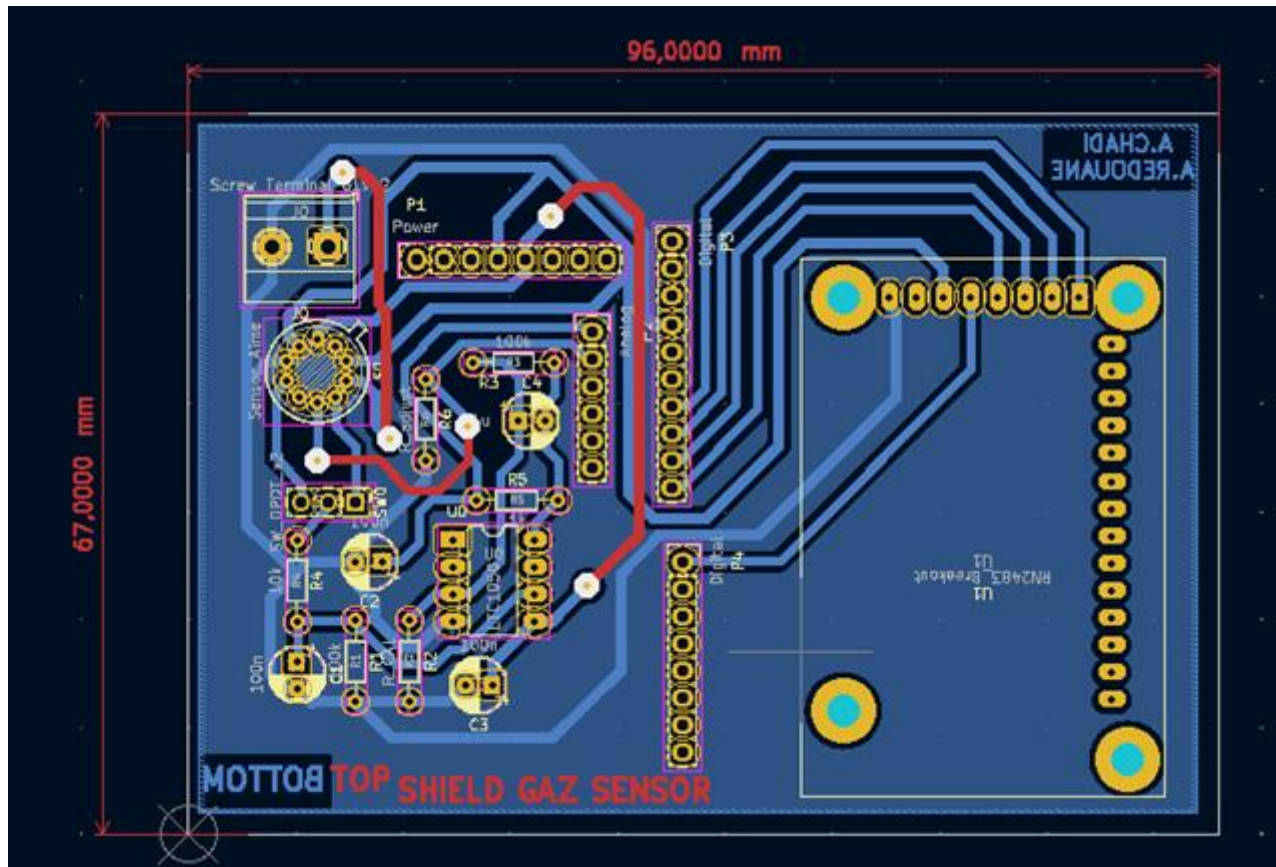
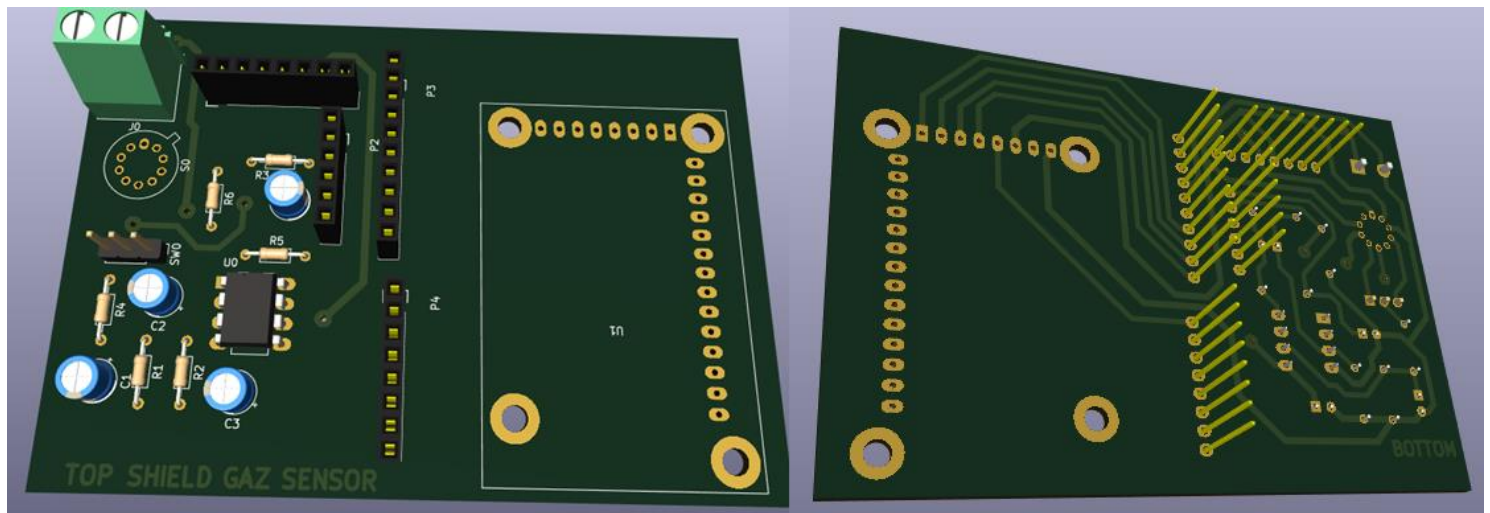


Figure8: File LTSpice Simulation

## KiCad shield for sensor integration



*Figure9: KiCad - Shield Gaz Sensor*



*Figure10: KiCad - Other view of our Shield Gaz Sensor*

